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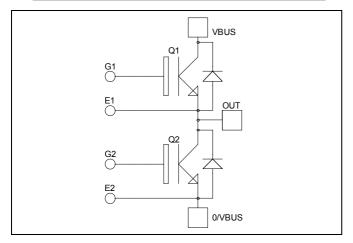
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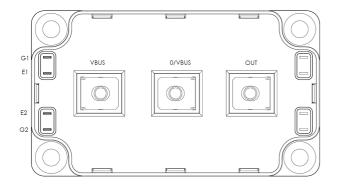
Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Phase leg Trench + Field Stop IGBT3 Power Module





V_{CES} = 1700V I_C = 225A @ Tc = 80°C

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Trench + Field Stop IGBT3 Technology
 - Low voltage drop
 - Low tail current
 - Switching frequency up to 20 kHz
 - Soft recovery parallel diodes
 - Low diode VF
 - Low leakage current
 - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
 - Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{CES}	Collector - Emitter Breakdown Voltage		1700	V
I _C	Continuous Collector Current	$T_C = 25^{\circ}C$	340	
	Continuous Conector Current	$T_C = 80^{\circ}C$	225	А
I _{CM}	Pulsed Collector Current	$T_C = 25^{\circ}C$	450	
V _{GE}	Gate – Emitter Voltage		±20	V
PD	Maximum Power Dissipation	$T_C = 25^{\circ}C$	1250	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^{\circ}C$	450A @ 1600V	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25^{\circ}C$ unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{CES}	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 1700V$				500	μA
V _{CE(sat)}	Collector Emitter Saturation Voltage	J GL SA SA	$T_j = 25^{\circ}C$		2.0	2.4	V
			$T_{j} = 125^{\circ}C$		2.4		v
V _{GE(th)}	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 4mA$		5.0	5.8	6.5	V
I _{GES}	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$ $f = 1MHz$			20		
Coes	Output Capacitance				0.8		nF
C _{res}	Reverse Transfer Capacitance				0.66		
T _{d(on)}	Turn-on Delay Time	Inductive Switch	ning (25°C)		370		
T _r	Rise Time		$V_{GE} = 15V$		40		ns
$T_{d(off)}$	Turn-off Delay Time	$V_{Bus} = 900V$ $I_{C} = 225A$ $R_{G} = 3.3\Omega$			650		
$T_{\rm f}$	Fall Time				180		
T _{d(on)}	Turn-on Delay Time	Inductive Switching (125°C) $V_{GE} = 15V$ $V_{Bus} = 900V$ $I_C = 225A$ $R_G = 3.3\Omega$			400		ns
Tr	Rise Time				50		
T _{d(off)}	Turn-off Delay Time				800		
T _f	Fall Time				300		
Eon	Turn-on Switching Energy	$V_{GE} = 15V$ $V_{Bus} = 900V$	$T_j = 125^{\circ}C$		72		mJ
E _{off}	Turn-off Switching Energy	$I_{\rm C} = 225 A$ $R_{\rm G} = 3.3 \Omega$	$T_j = 125^{\circ}C$		70.5		111)

Reverse diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage			1700			V
I _{RM}	Maximum Reverse Leakage Current	V _R =1700V	$T_j = 25^{\circ}C$			500	μA
Tun			$T_{j} = 125^{\circ}C$			750	
$I_{\rm F}$	DC Forward Current		$Tc = 80^{\circ}C$		225		Α
V _F	Diode Forward Voltage	$I_{\rm F} = 225 {\rm A}$	$T_j = 25^{\circ}C$		1.8	2.2	V
• F			$T_i = 125^{\circ}C$		1.9		·
t _{rr}	Reverse Recovery Time	L - 225A	$T_j = 25^{\circ}C$		385		ns
۹rr			$T_j = 125^{\circ}C$		490		115
0	Reverse Recovery Charge	$I_{\rm F} = 225 {\rm A}$ $V_{\rm R} = 900 {\rm V}$ di/dt = 2400 {\rm A}/{\mu s}	$T_j = 25^{\circ}C$		57		μC
Q _{rr}			$T_{j} = 125^{\circ}C$		93		μΟ
Er	Reverse Recovery Energy	covery Energy	$T_j = 25^{\circ}C$		26		mJ
L	Reverse Recovery Energy		$T_{j} = 125^{\circ}C$		52		1113

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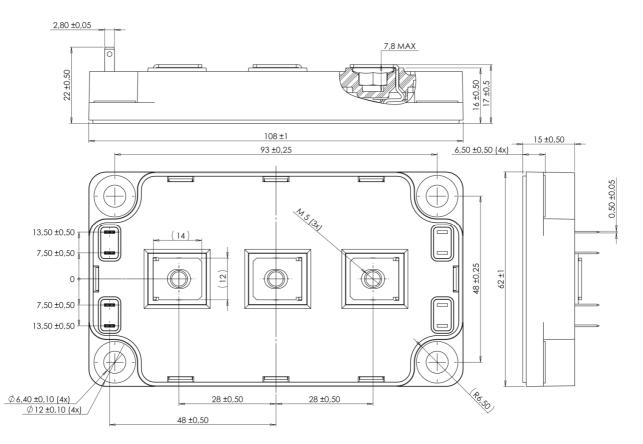
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Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R _{thJC}	Junction to Case Thermal Resistance IGBT Diode		IGBT			0.1	°C/W
R _{th} JC			Diode			0.18	C/ W
V _{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T _J	Operating junction temperature range			-40		150	
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M6	3		5	N.m
		For terminals	M5	2		3.5	19.111
Wt	Package Weight					300	g

SP6 Package outline (dimensions in mm)

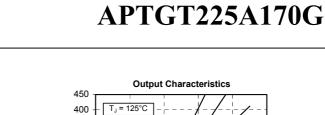


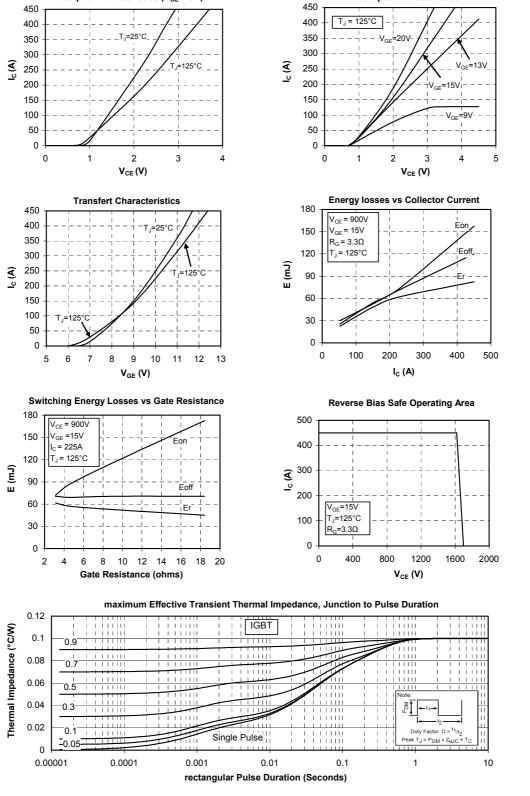
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



Output Characteristics (V_{GE}=15V)

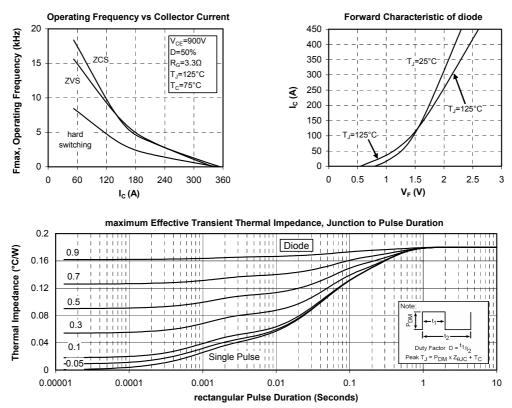
Typical Performance Curve





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